NSN 5961-01-232-3413

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-232-3413 **Inclosure Material:** Ceramic **Overall Length:** Between 0.660 inches and 0.785 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 drain to source voltage all transistor **Current Rating Per Characteristic:** 0.50 amperes on-state drain current all transistor **Power Rating Per Characteristic:** 1.2 watts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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